NSN 5961-01-619-3622

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-619-3622 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.225 inches **Overall Diameter:** Between 0.065 inches and 0.110 inches **End Application:** 1440-01-393-6361; launcher, guided missle, aircraft **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 25.0 amperes peak forward surge current **Power Rating Per Characteristic:** 500.0 watts reverse power dissipation, peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Short-body unleaded or surface mounted diodes (square end-caps) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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